

Schottky Barrier Diode, 1A, 40V Type

■FEATURES

Low Forward voltage Environmentally Friendly

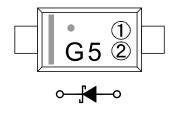
: EU RoHS Compliant, Pb Free

■ PRODUCT NAME

PRODUCT NAME	PACKAGE	ORDER UNIT
XBS104P11R-G *	SOD-123P	3,000/Reel

* The "-G" suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

MARKING

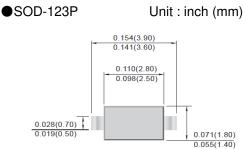


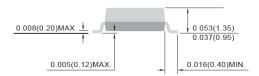
12: Control Number

■ APPLICATIONS

- Rectification
- Protection against reverse connection of battery

PACKAGING INFORMATION





■ABSOLUTE MAXIMUM RATINGS

Ta=25°C

PARAMETER	SYMBOL	RATINGS	UNITS
Repetitive Peak Reverse Voltage	V _{RM}	40	V
Reverse Voltage (DC)	V _R	40	V
Forward Current (Average) at Ta=75°C	I _{F(AV)}	1	А
Non Continuous Forward Surge Current (8.3 ms single half-sine wave)	I _{FSM}	30	A
Junction Temperature	Tj	125	°C
Storage Temperature	Tstg	-55 to +150	°C

ELECTRICAL CHARACTERISTICS

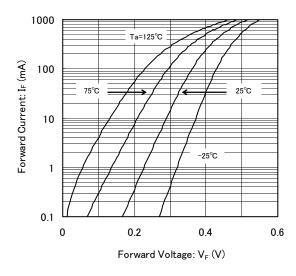
Ta=25°C

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
PARAMETER			MIN.	TYP.	MAX.	UNITS
Forward Voltage	V _F	I _F =1A	-	-	0.56	V
Reverse Current	I _R	I _R V _R =40V			500	μA
Terminal Capacitance	Ct	V _R =0V, f=1MHz	-	-	230	pF

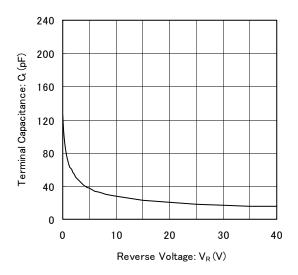
XBS104P11R-G

■TYPICAL PERFORMANCE CHARACTERISTICS

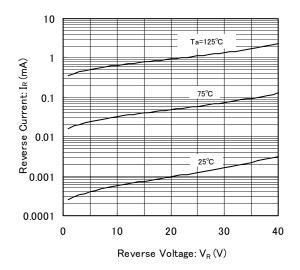
(1) Forward Current vs. Forward Voltage



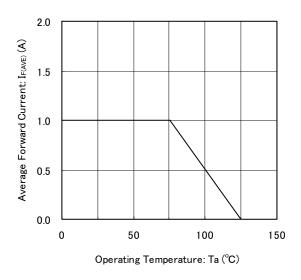
(3) Terminal Capacitance vs. Reverse Voltage



(2) Reverse Current vs. Reverse Voltage



(4) Average Forward Current vs. Operating Temperature



■NOTES ON USE

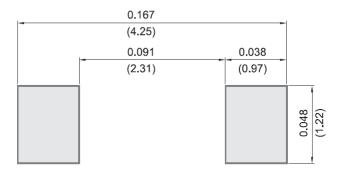
Please use this IC within the absolute maximum ratings.
 Even within the ratings, in case of high load use continuously such as high temperature, high voltage, high current and thermal stress may cause reliability degradation of the IC.

Torex places an importance on improving our products and their reliability.
 We request that users incorporate fail-safe designs and post-aging protection treatment when using Torex products in their systems.

■REFERENCE PATTERN LAYOUT

●SOD-123P

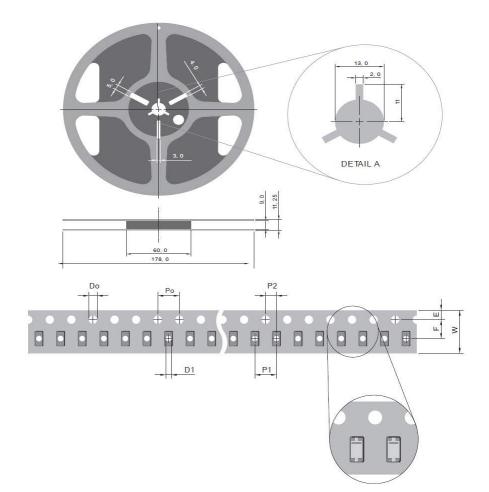
Unit : inch (mm)



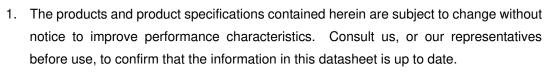
XBS104P11R-G

■TAPING SPECIFICATIONS

●SOD-123P



SYMBOL	mm
D ₀	1.50 ± 0.10
D1	1.00 ± 0.25
E	1.75 ± 0.10
F	3.50 ± 0.05
P ₀	4.00 ± 0.10
P1	4.00 ± 0.10
P2	2.00 ± 0.05
W	+ 0.15 8.00 - 0.15



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